Appl. No.

: 10/807,129

Filed

: March 24, 2004

AMENDMENTS TO THE CLAIMS

Claims 1-12 were pending prior to the entry of these amendments. Please amend Claims 1, 5, and 9-11.

1. (Currently Amended) An optical interference display unit at least comprising:

a first electrode;

a second electrode, in parallel with the first electrode and comprising:

a first material layer; and

a conductive layer on the first material layer; and

a support structure partially covered by the second electrode and supporting [[a]] an edge of the second electrode;

wherein a material of the conductive layer is more difficult to etch etched than a material of the <u>first</u> material <u>layer</u>.

- 2. (Original) The optical interference display unit of claim 1, wherein the optical interference display unit is located on a substrate.
- 3. (Original) The optical interference display unit of claim 2, wherein the substrate is a transparent substrate.
- 4. (Original) The optical interference display unit of claim 1, wherein a material of the first electrode is a conductive transparent material.
- 5. (Currently Amended) The optical interference display unit of claim 4, wherein the conductive transparent material is indium tin oxide (ITO), indium zinc oxide (IZO), or indium oxide [[(10)]] (IO).
- 6. (**Original**) The optical interference display unit of claim 1, wherein the second electrode is a deformable electrode.
- 7. (Original) The optical interference display unit of claim 1, wherein the second electrode is a movable electrode.
- 8. (Original) The optical interference display unit of claim 1, wherein a material for forming the support structure is selected from a group consisting of positive photoresist, negative photoresist, acrylic resin and epoxy resin.

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9. (Currently Amended) The optical interference display unit of claim 1, wherein the <u>first</u> material layer is made from a conductive material.

- 10. (Currently Amended) The optical interference display unit of claim 1, wherein the first material layer is made from dielectric material.
- 11. (Currently Amended) The optical interference display unit of claim 9, wherein a material for forming the <u>first</u> material layer is aluminum, chromium, cobalt, copper, silicon nitride or silicon oxide.
- 12. (Previously Presented) The optical interference display unit of claim 1, wherein a material for forming the conductive layer is aluminum, chromium, cobalt, copper, silicon nitride or silicon oxide.

13.-21. (Canceled)